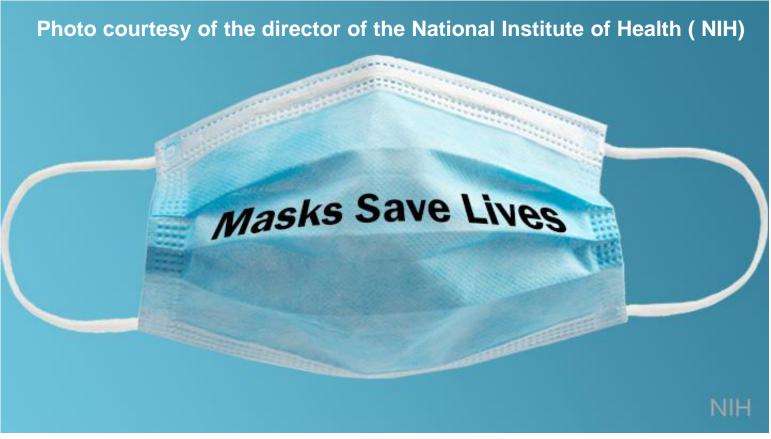
EE 330 Lecture 2

Basic Concepts



As a courtesy to fellow classmates, TAs, and the instructor

Wearing of masks during lectures and in the laboratories for this course would be appreciated irrespective of vaccination status

Grading Policy

3 Exams100 pts each1 Final100 pts.Homework100 pts.totalLab and Lab Reports100 pts.totalDesign Project100 pts.

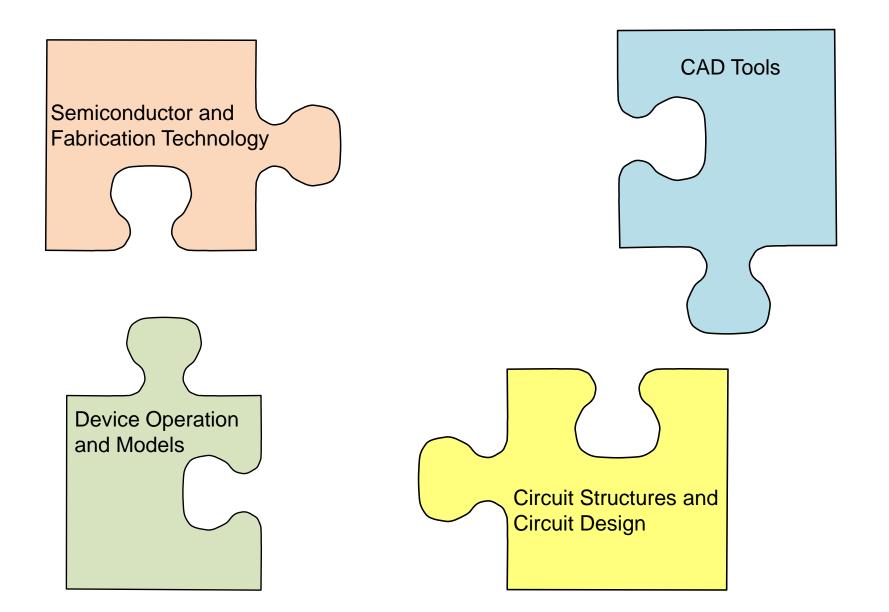
- A letter grade will be assigned based upon the total points accumulated
- Grade breaks will be determined based upon overall performance of the class

Equal Access Policy

Participation in all class functions and provisions for special circumstances including special needs will be in accord with ISU policy

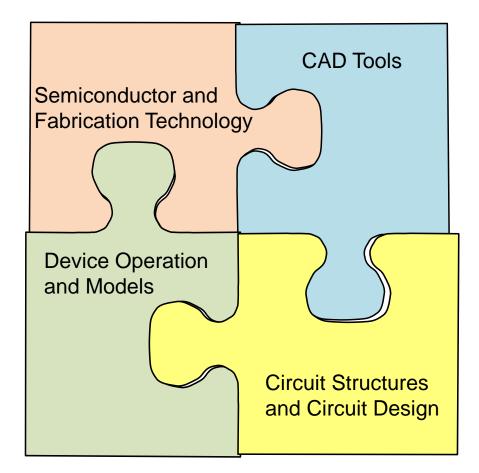
Participation in any classes or laboratories, turning in of homework, or taking any exams is optional however grades will be assigned in accord with the described grading policy. No credit will be given for any components of the course without valid excuse if students choose to not contribute. Successful completion of ALL laboratory experiments and submission of complete laboratory reports for ALL laboratory experiments to TA by deadline established by laboratory instructor is, however, required to pass this course.

Review from last lecture: How Integrated Electronics will be Approached

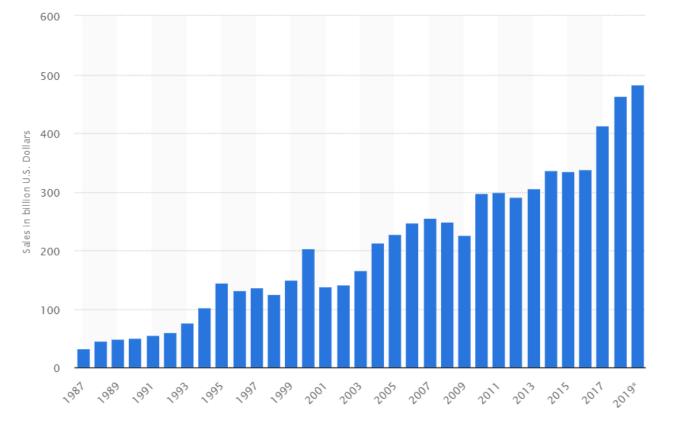


How Integrated Electronics will be Approached

After about four weeks, through laboratory experiments and lectures, the concepts should come together



How big is the semiconductor industry?



Projected at \$483 Billion in 2019

Semiconductor sales do not include the sales of the electronic systems in which they are installed and this marked is much bigger !!



The Semiconductor Industry How big is it ?

About \$470B/Year and growing

How does it compare to Iowa-Centric Commodities?

Larger than major agricultural commodities (close to 3.5X)

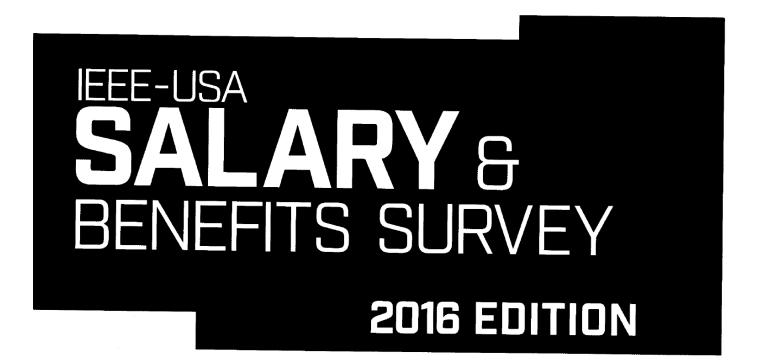
The semiconductor industry is one of the largest sectors in the world economy and continues to grow

Is an automobile an electronics "gadget"?



Rewards in the Electronics Field

Can engineers working in the semiconductor electronics field make a good living?



2015 Primary Income by Primary Area of Technical Competence

| | Number of Cases | Lowest Decile | Lower Quartile | Median | Upper Quartile | Highest Decile |
|--|--------------------|------------------|-------------------|--------------------|-----------------------|-------------------|
| | 7,391 | \$79,200 | \$103,000 | \$135,000 | \$173,000 | \$223,000 |
| CIRCUITS AND DEVICES | 1,127 | \$85,000 | \$110,000 | \$144,700 | \$182,878 | \$240,000 |
| Circuits and Systems | 416 | \$79,750 | \$100,991 | \$130,000 | \$165,000 | \$210,000 |
| Components, Packaging and Manufacturing Technology | 94 | \$103,200 | \$120,188 | \$153,850 | \$190,700 | \$258,800 |
| Electronic Devices | 239 | \$80,000 | \$105,034 | \$141,458 | \$186,372 | \$235,240 |
| Lasers and Electro-Optics | 79 | \$83,800 | \$112,915 | ¢150.000 | \$184,000 | \$222,800 |
| Solid-State Circuits | 277 | \$105,030 | \$134,000 | \$165,000 | \$204,700 | \$265,168 |
| Other | 25 | \$72,380 | \$107,000 | \$130,000 | \$208,000 | \$332,175 |
| COMMUNICATIONS TECHNOLOGY | 581 | \$87,000 | \$114,000 | \$152,500 | \$196,000 | \$250,000 |
| Broadcast Technology | 46 | \$64,500 | \$97,500 | \$141,500 | \$198,000 | \$326,250 |
| Communications | 419 | \$87,400 | \$114,945 | \$153,000 | \$193,28 9 | \$246,37 |
| Consumer Electronics | 42 | \$94,150 | \$105,750 | \$156,500 | \$188,750 | \$256,50 |
| Vehicular Technology | 21 | - | - | - | - | |
| Other | 61 | \$93,441 | \$122,400 | \$163,000 | \$208,099 | \$270,00 |
| COMPUTERS | 1,545 | \$80,000 | \$103,500 | \$138,941 | \$180,000 | \$233,61 |
| Hardware | 246 | \$90,000 | \$110,000 | \$143,702 | \$182,625 | \$254,26 |
| Non-Internet Software Development | 591 | \$80,000 | \$101,000 | \$136,000 | \$176,928 | \$226,00 |
| Non-Internet Systems Analysis/Integration | 179 | \$83,800 | \$102,583 | \$130,000 | \$173,726 | \$221,85 |
| Non-Internet Software Applications including Database Admin. | 90 | \$65,260 | \$100,415 | \$132,500 | \$165,825 | \$222,50 |
| Internet/Web Development/Applications | 220 | \$73,538 | \$106,875 | \$139,800 | \$181,438 | \$256,75 |
| Other | 224 | \$80,300 | \$108,172 | \$147,500 | \$181,875 | \$234,29 |
| ELECTROMAGNETICS AND RADIATION | 420 | \$84,900 | \$110,000 | \$137,9 1 2 | \$169,606 | \$204,65 |
| Antennas and Propagation | 103 | \$78,720 | \$116,100 | \$140,000 | \$172,000 | \$197,36 |
| Electromagnetic Compatibility | 65 | \$76,800 | \$96,000 | \$123,079 | \$155,000 | \$180,60 |
| Magnetics | 26 | \$90,500 | \$109,472 | \$145,000 | \$180,902 | \$241,00 |
| Microwave Theory and Techniques | 114 | \$79,200 | \$105,314 | \$133,526 | \$168,344 | \$200,65 |
| Nuclear and Plasma Sciences | 70 | \$87,660 | \$113,725 | \$139,000 | \$159,825 | \$192,66 |
| Other | 50 | \$102,000 | \$121,500 | \$150,000 | \$184,600 | \$220,00 |
| ENERGY AND POWER ENGINEERING | 1,597 | \$75,000 | \$94,450 | \$121,000 | \$152,000 | \$192,00 |
| | | | | | | |

How much would it cost to download a 2-hour HDTV "movie" using compressed audio and video on a Verizon Smart Phone today? Assume total signal compressed to 14MB/sec

Verizon Data Plan of Jan 2016 \$3.50/GB

Total bytes: 43,000 GB/14 = 3070 GB = 3.1 TB

Total cost: \$10,745

Moving audio and video data is still expensive and still challenging !

Data costs for cellular communications are dropping ? (Verizon data plan of April 2014 is \$15/GB from 1G to 3G increment) (Verizon data plan of Aug 2015 is \$7.50/GB from 1G to 3G increment) (Verizon data plan of Aug 2018 is \$15/GB over plan limit if not unlimited)

S70/mo You like to stream video and are always online (great for

8GB

Premium 4G LTE Data Unlimited Talk & Text Carryover Data Safety Mode Data Boost \$15/1 GB Verizon Up Rewards

lan cost per month, plus \$20imo/line access fee pe martphone purchased on device payment. Plus xxes & fees.

Challenge to Students

- Become aware of how technology operates
- Identify opportunities where electronics technology can be applied
- Ask questions about how things operate and why

Selected Semiconductor Trends

- Microprocessors
- DRAMS
- FPGA

Best Processors August 2021

| hoose ca | X DESKTOP X | | Choose min rating | Search Model name | C |
|----------|---------------------------------|---------------|----------------------|----------------------|-------------------|
| LAPTOP | | | | Model name | |
| Rank | Device | MSRP Price | 3DMark Physics Score | ✔ Value for Money | Popularity |
| 1 | AMD Ryzen 9 5950X | \$799 | 14076 | 17 | 3.5 |
| 2 | Intel Core i9-10900K Processor | \$488 | 13768 | 28 | 2.7 |
| 3 | Intel Core i9-10900KF Processor | \$463 | 13593 | 29 | <mark>0</mark> .6 |
| 4 | Intel Core i9-10850K Processor | \$453 | 13440 | 29 | 1.5 |
| 5 | AMD Ryzen 9 5900X | \$549 | 13401 | 24 | 6.6 |
| 6 | AMD Ryzen 9 3950X | \$749 | 13231 | 17 | <mark>0.</mark> 9 |

| 7 | Intel Core i9-9960X Processor ★ ★ ★ ★ ★ DirectX 12.00 | n/a | 13076 | n/a | 0.0 |
|----|---|--------|-------|-----|-----|
| 8 | Intel Core i9-11900K Processor | \$539 | 12762 | 23 | 0.3 |
| 9 | Intel Core i9-7980XE Processor ★ ★ ★ ★ DirectX 12.00 | \$1979 | 12376 | 6 | 0.1 |
| 10 | Intel Core i9-10900 Processor * * * * * DirectX 12.00 | \$440 | 12278 | 27 | 0.1 |
| 11 | AMD Ryzen Threadripper 3960X ★ ★ ★ ★ DirectX 12.00 | \$1399 | 12248 | 8 | 0.1 |
| 12 | AMD Ryzen 9 3900XT ★ ★ ★ ★ ★ DirectX 12.00 | \$499 | 12124 | 24 | 0.4 |
| 13 | AMD Ryzen 9 3900X | \$499 | 12120 | 24 | 3.2 |

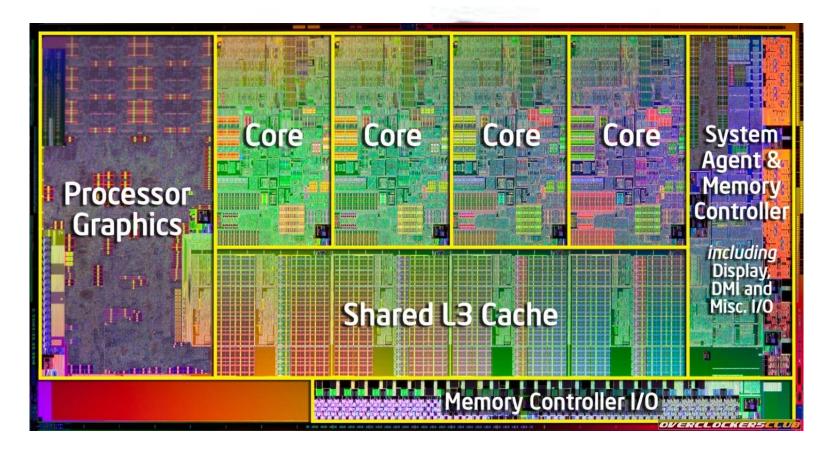
Spec Breakout: Key Comparison CPUs

| | AMD Ryzen 9 3900X | Intel Core i9-10900K | | |
|---------------------|-------------------|----------------------|--|--|
| List Price | \$499 | \$488 | | |
| Cores | 12 | 10 | | |
| Threads Supported | 24 | 20 | | |
| Base Clock | 3.8GHz | 3.7GHz | | |
| Boost Clock | 4.6GHz | 5.3GHz | | |
| Integrated Graphics | None | Intel UHD 630 | | |
| TDP Rating | 105 watts | 125 watts | | |
| Socket | AM4 | LGA1200 | | |

| AMD Ryzen 9 3900X (64-bit, SIMD, caches, I/O die) 9,890,000,000 ^{[1][2]} | 2019 | AMD | 7 & 12 nm (TSMC) | 273 mm ² |
|---|------|-----|---------------------|---------------------|
|---|------|-----|---------------------|---------------------|

Intel Core i9 10900K 14nm CMOS

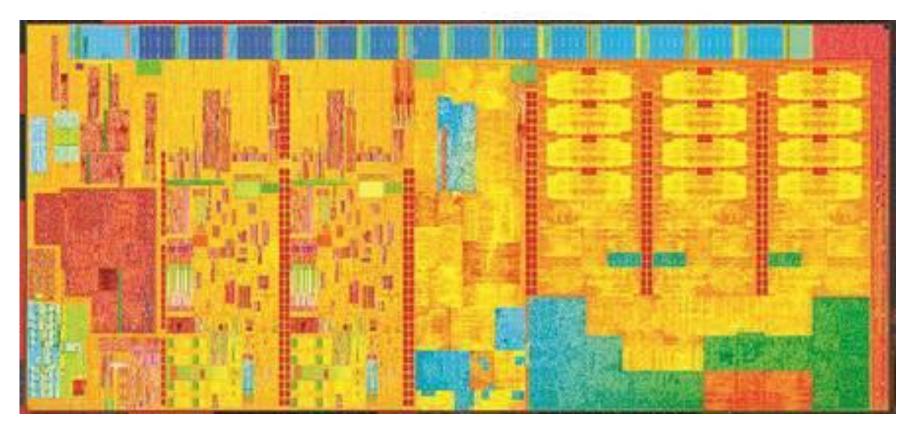
Recent Intel Processor



Processor

Quad-Core Intel[®] Core i7 Processor Up to 3.4GHz in 32nm CMOS Power Dissipation: 95 watts

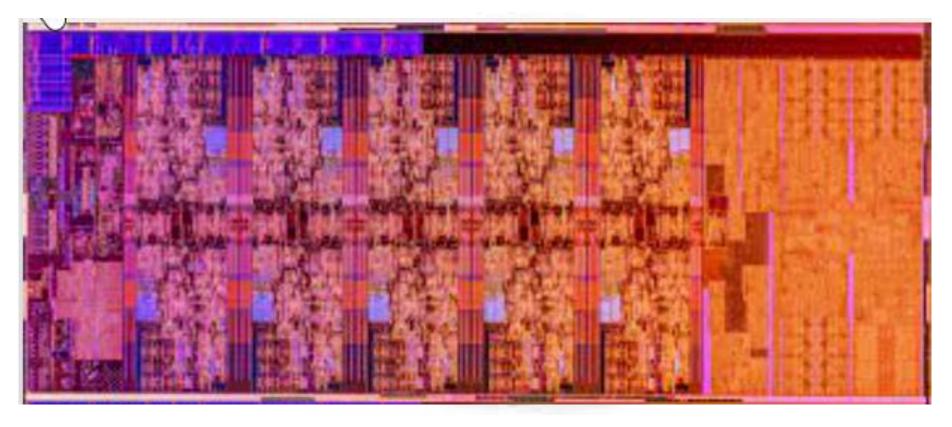




Processor

8-core (2.6B) or 18-core Broadwell Intel[®] Core M Processor in 14nm CMOS Intel Tic-Toc product ("Toc" from 22nm Haswell processor) Power Dissipation: 4.9 watts



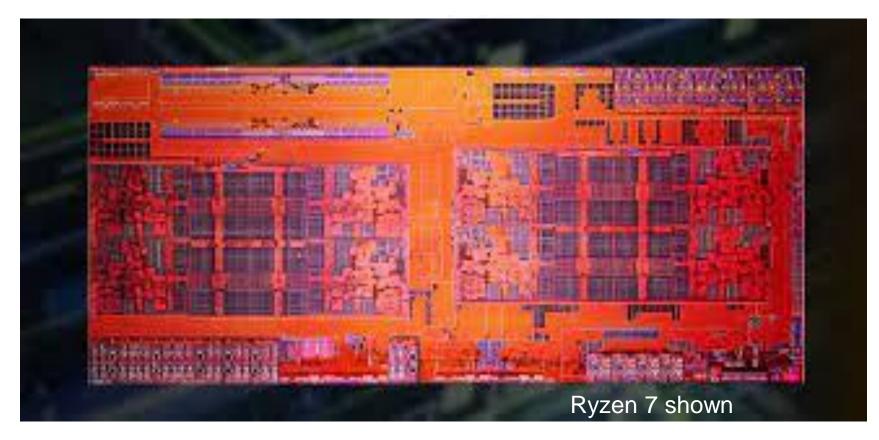


Processor Intel Core i9 10900K

10-core Processor in 14nm CMOS, 3.7GHz

Power Dissipation: 125 watts



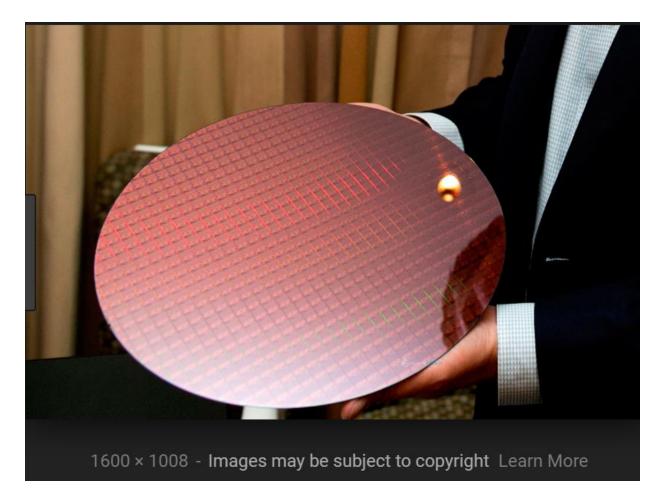


Processor AMD Ryzen 5950X

16-core Processor in 7nm CMOS, 3.4-4.9 GHz

Power Dissipation: 105 watts

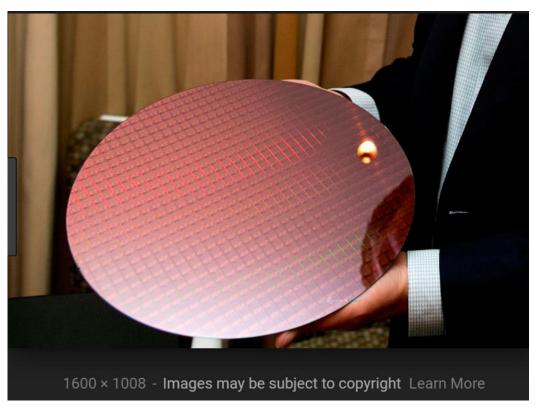
A bit ago!



Cannon Lake Processor

10nm CMOS i3-8121U Delayed production schedule – expected to ramp up in 2019

A bit ago!



Cannon Lake Processor

Press release from Intel - May 28, 2019

But now, <u>after years of delays</u>, the company is about to bring its first real batch* of 10nm CPUs to the world. Today, the company is officially taking the wraps off its 10th Gen Intel Core processors, codename "Ice Lake," and revealing some of what they might be able to do for your next PC when they ship in June.

Update: Intel discontinued the Cannon Lake Processor on Feb 28, 2020

Yesterday!

Processors

| Processor | MOS transistor count | Date of introduction ◆ | Designer 🔶 | MOS process ✦ (nm) | Area (mm²) 🗧 |
|--|--|---------------------------|--------------------|--------------------------|--------------------|
| MP944 (20-bit, 6-chip, 28 chips total) | 74,442 (5,360 excl. ROM & RAM) ^{[24][25]} | 1970 ^{[22][a]} | Garrett AiResearch | ? | ? |
| Intel 4004 (4-bit, 16-pin) | 2,250 | 1971 | Intel | 10,000 nm | 12 mm^2 |
| TMX 1795 (?-bit, 24-pin) | 3,078 ^[26] | 1971 | Texas Instruments | ? | 30 mm ² |
| Intel 8008 (8-bit, 18-pin) | 3,500 | 1972 | Intel | 10,000 nm | 14 mm ² |
| NEC µCOM-4 (4-bit, 42-pin) | 2,500 ^{[27][28]} | 1973 | NEC | 7,500 nm ^[29] | ? |
| Toshiba TLCS-12 (12-bit) | 11,000+ ^[30] | 1973 | Toshiba | 6,000 nm | 32 mm ² |
| Intel 4040 (4-bit, 16-pin) | 3,000 | 1974 | Intel | 10,000 nm | 12 mm ² |
| Motorola 6800 (8-bit, 40-pin) | 4,100 | 1974 | Motorola | 6,000 nm | 16 mm ² |
| Intel 8080 (8-bit, 40-pin) | 6,000 | 1974 | Intel | 6,000 nm | 20 mm ² |
| TMS 1000 (4-bit, 28-pin) | 8,000 | 1974 ^[31] | Texas Instruments | 8,000 nm | 11 mm ² |
| MOS Technology 6502 (8-bit, 40-pin) | 4,528 ^{[b][32]} | 1975 | MOS Technology | 8,000 nm | 21 mm ² |
| Intersil IM6100 (12-bit, 40-pin; clone of PDP-8) | 4,000 | 1975 | Intersil | ? | ? |
| CDP 1801 (8-bit, 2-chip, 40-pin) | 5,000 | 1975 | RCA | ? | ? |
| RCA 1802 (8-bit, 40-pin) | 5,000 | 1976 | RCA | 5,000 nm | 27 mm ² |
| Zilog Z80 (8-bit, 4-bit ALU, 40-pin) | 8,500 ^[c] | 1976 | Zilog | 4,000 nm | 18 mm ² |
| Intel 8085 (8-bit, 40-pin) | 6,500 | 1976 | Intel | 3,000 nm | 20 mm ² |
| TMS9900 (16-bit) | 8,000 | 1976 | Texas Instruments | ? | ? |
| | | | | | |



Processors

| Tegra Xavier SoC (64/32-bit) | 9,000,000,000 ^[127] | 2018 | Nvidia | 12 nm | 350 mm ² |
|---|--------------------------------------|------|-------------------|---------------------|------------------------------|
| AMD Ryzen 7 3700X (64-bit, SIMD, caches, I/O die) | 5,990,000,000 ^{[128][d]} | 2019 | AMD | 7 & 12 nm (TSMC) | 199 (74+125) mm ² |
| HiSilicon Kirin 990 4G | 8,000,000,000 ^[129] | 2019 | Huawei | 7 nm | 90.00 mm ² |
| Apple A13 (hexa-core 64-bit ARM64 "mobile SoC", SIMD, caches) | 8,500,000,000 ^{[130][131]} | 2019 | Apple | 7 nm | 98.48 mm ² |
| AMD Ryzen 9 3900X (64-bit, SIMD, caches, I/O die) | 9,890,000,000 ^{[1][2]} | 2019 | AMD | 7 & 12 nm (TSMC) | 273 mm ² |
| HiSilicon Kirin 990 5G | 10,300,000,000 ^[132] | 2019 | Huawei | 7 nm | 113.31 mm ² |
| AWS Graviton2 (64-bit, 64-core ARM-based, SIMD, caches) ^{[133][134]} | 30,000,000,000 | 2019 | Amazon | 7 nm | ? |
| AMD Epyc Rome (64-bit, SIMD, caches) | 39,540,000,000 ^{[1][2]} | 2019 | AMD | 7 & 12 nm (TSMC) | 1008 mm ² |
| TI Jacinto TDA4VM (ARM A72, DSP, SRAM) | 3,500,000,000 ^[135] | 2020 | Texas Instruments | 16 nm | |
| Apple A14 Bionic (hexa-core 64-bit ARM64 "mobile SoC", SIMD, caches) | 11,800,000,000 ^[136] | 2020 | Apple | 5 nm | 88 mm ² |
| Apple M1 (octa-core 64-bit ARM64 SoC, SIMD, caches) | 16,000,000,000 ^[137] | 2020 | Apple | 5 nm | 19 mm ² |
| HiSilicon Kirin 9000 | 15,300,000,000 ^{[138][139]} | 2020 | Huawei | 5 nm | 114 mm ² |

Today!

| FPGA 🗢 | MOS transistor count + | Date of introduction \$ | Designer 🕈 | Manufacturer 🗢 | MOS process + | Area 🗢 | Ref |
|--------------------------|------------------------|--------------------------------|------------|----------------|---------------|--------------------------|-----------------|
| Virtex | 70,000,000 | 1997 | Xilinx | | | | |
| Virtex-E | 200,000,000 | 1998 | Xilinx | | | | |
| Virtex-II | 350,000,000 | 2000 | Xilinx | | 130 nm | | |
| Virtex-II PRO | 430,000,000 | 2002 | Xilinx | | | | |
| Virtex-4 | 1,000,000,000 | 2004 | Xilinx | | 90 nm | | |
| Virtex-5 | 1,100,000,000 | 2006 | Xilinx | TSMC | 65 nm | | [195] |
| Stratix IV | 2,500,000,000 | 2008 | Altera | TSMC | 40 nm | | [196] |
| Stratix V | 3,800,000,000 | 2011 | Altera | TSMC | 28 nm | | [197] |
| Arria 10 | 5,300,000,000 | 2014 | Altera | TSMC | 20 nm | | [198] |
| Virtex-7 2000T | 6,800,000,000 | 2011 | Xilinx | TSMC | 28 nm | | [199] |
| Stratix 10 SX 2800 | 17,000,000,000 | TBD | Intel | Intel | 14 nm | 560 mm ² | [200][201] |
| Virtex-Ultrascale VU440 | 20,000,000,000 | Q1 2015 | Xilinx | TSMC | 20 nm | | [202][203] |
| Virtex-Ultrascale+ VU19P | 35,000,000,000 | 2020 | Xilinx | TSMC | 16 nm | 900 mm ^{2 [e]} | [204][205][206] |
| Versal VC1902 | 37,000,000,000 | 2H 2019 | Xilinx | TSMC | 7 nm | | [207][208][209] |
| Stratix 10 GX 10M | 43,300,000,000 | Q4 2019 | Intel | Intel | 14 nm | 1400 mm ^{2 [e]} | [210][211] |
| Versal VP1802 | 92,000,000,000 | 2021 ? ^[f] | Xilinx | TSMC | 7 nm | ? | [212][213] |

Memory Trends

| | 16 Mb | SRAM (CMOS) | 100,663,296 | 1992 | Fujitsu, NEC | 400 nm | 400 nm ? | | |
|-------|--------------|----------------|-----------------|-------------------|--------------|--------|----------|------------|--|
| 5 | 256 Mb | DRAM (CMOS) | 268,435,456 | 1993 | Hitachi, NEC | 250 nm | 1 | [234] | |
| 2 | | DDAM | 4 070 744 004 | 2 744 904 | NEC | 250 nm | ? | [240][241] | |
| | 1 Gb | DRAM | 1,073,741,824 | January 9, 1995 - | Hitachi | 160 nm | ? | נביטןנציון | |
| | SDRAM | 1,073,741,824 | 1996 | Mitsubishi | 150 nm | ? | [234] | | |
| | SDRAM (SOI) | 1,073,741,824 | 1997 | Hyundai | ? | ? | [242] | | |
| | DRAM (4-bit) | 1,073,741,824 | 1997 | NEC | 150 nm | ? | [234] | | |
| ? | 4 Gb | DRAM | 4,294,967,296 | 1998 | Hyundai | ? | ? | [242] | |
| | 8 Gb | SDRAM (DDR3) | 8,589,934,592 | April 2008 | 0 | 50 | 0 | [243] | |
| | 16 Gb | SDRAM (DDR3) | 17,179,869,184 | 2008 | Samsung | 50 nm | ? | [210] | |
| | 32 Gb | SDRAM (HBM2) | 34,359,738,368 | 2016 | 0 | 00 | 0 | [244] | |
| 64 Gb | SDRAM (HBM2) | 68,719.476,736 | 2017 | Samsung | 20 nm | ? | [214] | | |
| | 128 Gb | SDRAM (DDR4) | 137,438,953,472 | 2018 | Samsung | 10 nm | ? | [245] | |

Memory Trends

| ? | | | 500.070.040 | 0004 | Samsung | ? | ? | [234] |
|-------------|--------|--------------------------|-------------------|------------|------------------|--------------|---------------------|------------|
| | 1 Gb | 2-bit NAND | 536,870,912 | 2001 | Toshiba, SanDisk | 160 nm | ? | [251] |
| | 2 Gb | NAND | 2,147,483,648 | 2002 | Samsung, Toshiba | ? | ? | [252][253] |
| | 8 Gb | NAND | 8,589,934,592 | 2004 | Samsung | 60 nm | ? | [252] |
| | 16 Gb | NAND | 17,179,869,184 | 2005 | Samsung | 50 nm | ? | [254] |
| | 32 Gb | NAND | 34,359,738,368 | 2006 | Samsung | amsung 40 nm | | [] |
| THGAM | 128 Gb | Stacked NAND | 128,000,000,000 | April 2007 | Toshiba | 56 nm | 252 mm ² | [255] |
| THGBM | 256 Gb | Stacked NAND | 256,000,000,000 | 2008 | Toshiba | 43 nm | 353 mm ² | [256] |
| THGBM2 | 1 Tb | Stacked 4-bit NAND | 256,000,000,000 | 2010 | Toshiba | 32 nm | 374 mm ² | [257] |
| KLMCG8GE4A | 512 Gb | Stacked 2-bit NAND | 256,000,000,000 | 2011 | Samsung | ? | 192 mm ² | [258] |
| KLUFG8R1EM | 4 Tb | Stacked 3-bit V- NAND | 1,365,333,333,504 | 2017 | Samsung | ? | 150 mm ² | [259] |
| eUFS (1 TB) | 8 Tb | Stacked 4-bit V- NAND | 2,048,000,000,000 | 2019 | Samsung | ? | 150 mm ² | [4][260] |

FPGA Trends

| FPGA 🗢 | MOS transistor count \$ | Date of introduction \$ | Designer 🕈 | Manufacturer 🗢 | MOS process 🗢 | Area 🗢 | Ref |
|--------------------------|-------------------------|--------------------------------|------------|----------------|---------------|--------------------------|------------|
| Virtex | 70,000,000 | 1997 | Xilinx | | | | |
| Virtex-E | 200,000,000 | 1998 | Xilinx | | | | |
| Virtex-II | 350,000,000 | 2000 | Xilinx | | 130 nm | | |
| Virtex-II PRO | 430,000,000 | 2002 | Xilinx | | | | |
| Virtex-4 | 1,000,000,000 | 2004 | Xilinx | | 90 nm | | |
| Virtex-5 | 1,100,000,000 | 2006 | Xilinx | TSMC | 65 nm | | [195] |
| Stratix IV | 2,500,000,000 | 2008 | Altera | TSMC | 40 nm | | [196] |
| Stratix V | 3,800,000,000 | 2011 | Altera | TSMC | 28 nm | | [197] |
| Arria 10 | 5,300,000,000 | 2014 | Altera | TSMC | 20 nm | | [198] |
| Virtex-7 2000T | 6,800,000,000 | 2011 | Xilinx | TSMC | 28 nm | | [199] |
| Stratix 10 SX 2800 | 17,000,000,000 | TBD | Intel | Intel | 14 nm | 560 mm ² | [200][201] |
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| Virtex-Ultrascale+ VU19P | 35,000,000,000 | 2020 | Xilinx | TSMC | 16 nm | 900 mm ^{2 [e]} | [204][205] |
| Versal VC1902 | 37,000,000,000 | 2H 2019 | Xilinx | TSMC | 7 nm | | [207][208] |
| Stratix 10 GX 10M | 43,300,000,000 | Q4 2019 | Intel | Intel | 14 nm | 1400 mm ^{2 [e]} | [210][211] |
| Versal VP1802 | 92,000,000,000 | 2021 ? ^[f] | Xilinx | тѕмс | 7 nm | ? | [212][213] |

Special Purpose Systems

| Device type 🗢 | Device name ◆ | Transistor count ◆ | Date of introduction | Designer(s) ≑ | Manufacturer(s) 🗢 | MOS process | Area 🗢 | Ref |
|--|-------------------------|-----------------------|-------------------------|----------------------|-------------------|----------------|------------------------|---|
| Deep learning engine / IPU ^[g] | Colossus GC2 | 23,600,000,000 | 2018 | Graphcore | TSMC | 16 nm | ~800 mm ² | [295][296][297] [better source needed] |
| Deep learning engine / IPU | Wafer Scale Engine | 1,200,000,000,000 | 2019 | Cerebras | TSMC | 16 nm | 46,225 mm ² | [5][6][7][8] |
| Deep learning engine / IPU | Wafer Scale Engine 2 | 2,600,000,000,000 | 2020 | Cerebras | тѕмс | 7 nm | 46,225 mm ² | [9][298] |

Selected Semiconductor Trends

- Microprocessors
 - State of the art technology is now 5 nm with over 40
 Billion transistors on a chip
- DRAMS
 - State of the art is now 128G bits on a chip in a 10nm process which requires somewhere around 140 Billion transistors
- FPGA
 - FPGAs currently have over 90 Billion transistors with 7nm technology and are growing larger
 Device count on a chip has been increasing rapidly with time, device size has been decreasing rapidly with time and speed/performance has been rapidly increasing

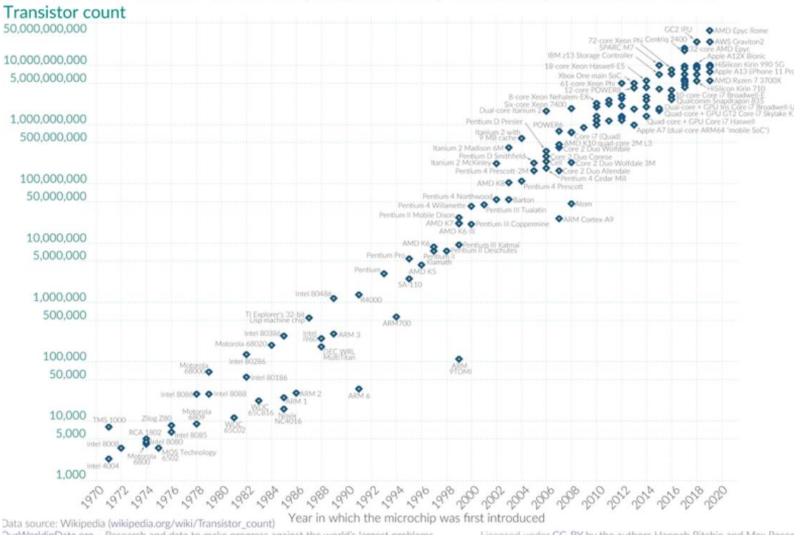
Moore's Law

From Webopedia (Aug 2016)

The observation made in 1965 by Gordon Moore, co-founder of <u>Intel</u>, that the number of <u>transistors</u> per square inch on <u>integrated circuits</u> had doubled every year since the integrated circuit was invented. Moore predicted that this trend would continue for the foreseeable future. In subsequent years, the pace slowed down a bit, but <u>data</u> density has doubled approximately every 18 months, and this is the current definition of Moore's Law, which Moore himself has blessed. Most experts, including Moore himself, expect Moore's Law to hold for at least another two decades.

Moore's Law: The number of transistors on microchips doubles every two years Our World in Data

Moore's law describes the empirical regularity that the number of transistors on integrated circuits doubles approximately every two years. This advancement is important for other aspects of technological progress in computing – such as processing speed or the price of computers.



More on Moore's Law

| MIT Toobhology | Lo | g in / Register Search Q | | | | |
|--|---------------------------------|-----------------------------------|---------------------------------------|--------------------------|--|--|
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| S redhat | SEE HOW WITH open technologies. | ART EXPLORING | | | | |
| Intelligent Machines Moore's Law Is Dead. Now What? | | SUBSCRIBE | SCIENTIFIC AMERICAN. | English 🗸 Cart 🧧 Sign In | | |
| Shrinking transistors have powe | | THE SCIENCES MIND HEALT | H TECH SUSTAINABILITY EDUCATION VIDEO | PODCASTS BLOGS STORE | | |
| computing—but now other ways must be found to make computers more capable. | | cinet | | | | |
| by Tom Simonite May 13, 2016 | | | TECH | | | |
| | | End of Moore's Law: It's not just | | | | |

Moore's Law's End Reboots Industry | EE Times

www.eetimes.com/document.asp?doc_id=1331941 ▼

Jun 26, 2017 - The expected death of **Moore's Law** will transform the ... four years, so were reaching the **end** of semiconductor technology as we know it," said ...

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about physics

News Semiconductors Devices

Transistors Could Stop Shrinking in 2021

A key industry report forecasts an end to traditional scaling of transistors

Posted 22 Jul 2016 | 13:04 GMT By RACHEL COURTLAND

Moore's Law Running Out of Room, Tech Looks for a Successor - The ...

https://www.nytimes.com/.../moores-law-running-out-of-room-tech-looks-for-a-successo... May 4, 2016 - "The **end** of **Moore's Law** is what led to this," said Thomas M. Conte, a Georgia Institute of Technology computer scientist and co-chairman of ...

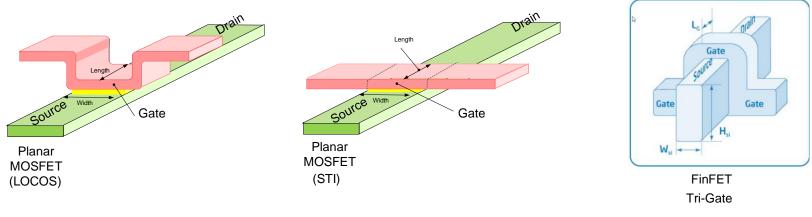
Moore's Law

From Wikopedia (Aug 2017)

....However, in April 2016, Intel CEO Brian Krzanich stated that "In my 34 years in the semiconductor industry, I have witnessed the advertised death of Moore's Law no less than four times. As we progress from 14 nanometer technology to 10 nanometer and plan for 7 nanometer and 5 nanometer and even beyond, our plans are proof that Moore's Law is alive and well".^[25] In January 2017, he declared that "I've heard the death of Moore's law more times than anything else in my career ... And I'm here today to really show you and tell you that Moore's Law is alive and flourishing."^[26]

Today hardware has to be designed in a <u>multi-core</u> manner to keep up with Moore's law. In turn, this also means that software has to be written in a <u>multi-threaded</u> manner to take full advantage of the hardware.

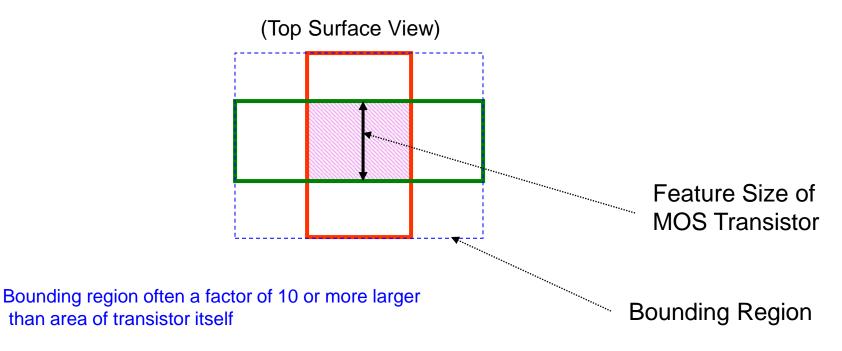
Field Effect Transistors



Dielectric not shown

Feature Size

The feature size of a process generally corresponds to the minimum lateral dimensions of the transistors that can be fabricated in the process



 This along with interconnect requirements and sizing requirements throughout the circuit create an area overhead factor of 10x to 100x

Moore's Law

(from Wikipedia)

Moore's law is the <u>empirical</u> observation that the <u>complexity</u> of <u>integrated</u> <u>circuits</u>, with respect to minimum component cost, doubles every 24 months[1]. It is attributed to <u>Gordon E. Moore[2]</u>, a co-founder of <u>Intel</u>.

- Observation, not a physical law
- Often misinterpreted or generalized
- Many say it has been dead for several years
- Many say it will continue for a long while
- Not intended to be a long-term prophecy about trends in the semiconductor field
- Something a reporter can always comment about when they have nothing to say!

Device scaling, device count, circuit complexity, device cost, ... in leadingedge processes will continue to dramatically improve (probably nearly geometrically with a time constant of around 2 years) for the foreseeable future !!

Challenges

- Managing increasing device count
- Short lead time from conception to marketplace
- Process technology advances
- Device performance degradation
- Increasing variability
- Increasing pressure for cost reduction
- Power dissipation

Future Trends and Opportunities

• Is there an end in sight?

No! But the direction the industry will follow is not yet known but the role semiconductor technology plays on society will increase dramatically!

• Will engineers trained in this field become obsolete at mid-career ?

No! Engineers trained in this field will naturally evolve to support the microelectronics technology of the future. Integrated Circuit designers are now being trained to efficiently manage enormous levels of complexity and any evolutionary technology will result in even larger and more complexity systems with similar and expanded skills being required by the engineering community with the major changes occurring only in the details.

Future Trends and Opportunities

 Will engineers trained in this field be doing things the same way as they are now at midcareer?

No! There have been substantive changes in approaches every few years since 1965 and those changes will continue. Continuing education to track evolutionary and revolutionary changes in the field will be essential to remain productive in the field.

 What changes can we expect to see beyond the continued geometric growth in complexity (capability) ?

That will be determined by the creativity and marketing skills of those who become immersed in the technology. New "Gordon Moores", "Bill Gates" and "Jim Dells" will evolve.

Creation of Integrated Circuits

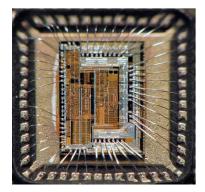
Most integrated circuits are comprised of transistors along with a small number of passive components and maybe a few diodes

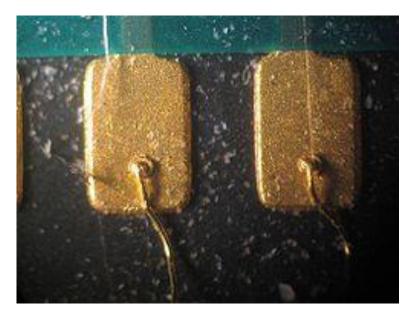
This course will focus on understanding how transistors operate and on how they can be interconnected and possibly combined with a small number of passive components to form useful integrated circuits

Wire Sizes for Electrical Interconnects



50 A Range Cord 6 ga Wiring 0.162 in diameter





25um Gold Bonding Wire



Stay Safe and Stay Healthy !

End of Lecture 2